# PH1214-100EL

## Radar Pulsed Power Transistor 100W, 1.2-1.4 GHz, 2ms Pulse, 20% Duty

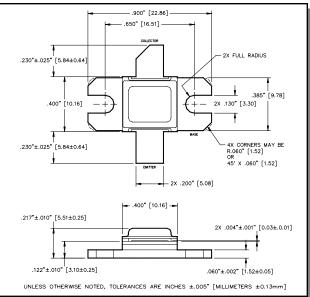
#### Features

- NPN silicon microwave power transistors
- Common base configuration
- Broadband Class C operation
- High efficiency inter-digitized geometry
- Diffused emitter ballasting resistors
- Gold metallization system
- · Internal input and output impedance matching
- Hermetic metal/ceramic package
- RoHS compliant



### M/A-COM Products Released, 30 May 07

#### **Outline Drawing**



#### Absolute Maximum Ratings at 25°C

Parameter	Symbol	Rating	Units
Collector-Emitter Voltage	V <sub>CES</sub>	75	V
Emitter-Base Voltage	V <sub>EBO</sub>	3.0	V
Collector Current (Peak)	Ι <sub>C</sub>	14.1	А
Power Dissipation @ +25°C	P <sub>TOT</sub>	250	W
Storage Temperature	T <sub>STG</sub>	-65 to +200	°C
Junction Temperature	TJ	200	°C

#### Electrical Specifications: T<sub>c</sub> = 25 ± 5°C (Room Ambient )

Parameter	Test Conditions	Frequency	Symbol	Min	Мах	Units
Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 50mA		BV <sub>CES</sub>	70	-	V
Collector-Emitter Leakage Current	V <sub>CE</sub> = 28V		I <sub>CES</sub>	-	10	mA
Thermal Resistance	Vcc = 28V, Pin = 25W	F = 1.2, 1.3, 1.4 GHz	R <sub>TH(JC)</sub>	-	0.7	°C/W
Output Power	Vcc = 28V, Pin = 25W	F = 1.2, 1.3, 1.4 GHz	P <sub>OUT</sub>	100	-	W
Power Gain	Vcc = 28V, Pin = 25W	F = 1.2, 1.3, 1.4 GHz	G <sub>P</sub>	6.0	-	dB
Collector Efficiency	Vcc = 28V, Pin = 25W	F = 1.2, 1.3, 1.4 GHz	η <sub>c</sub>	52	-	%
Input Return Loss	Vcc = 28V, Pin = 25W	F = 1.2, 1.3, 1.4 GHz	RL	-	-8	dB
Load Mismatch Tolerance	Vcc = 28V, Pin = 25W	F = 1.2, 1.3, 1.4 GHz	VSWR-T	-	3:1	-
Load Mismatch Stability	Vcc = 28V, Pin = 25W	F = 1.2, 1.3, 1.4 GHz	VSWR-S	-	1.5:1	-

ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed. **PRELIMINARY:** Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are

- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
  Visit www.macomtech.com for additional data sheets and product information.

typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed. M/A-COM Technology Solutions Inc. and its affiliates reserve the right to make charges withe product is) by information contained herein without notice.



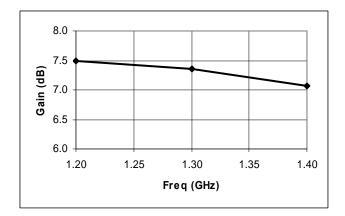
M/A-COM Products Released, 30 May 07

Radar Pulsed Power Transistor
100W, 1.2-1.4 GHz, 2ms Pulse, 20% Duty

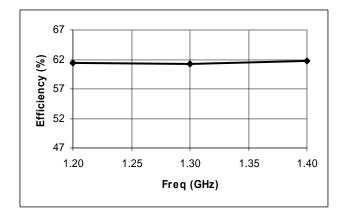
# Typical RF Performance

Freq. (GHz)	Pin (W)	Pout (W)	Gain (dB)	lc (A)	Eff (%)	RL (dB)	VSWR-S (1.5:1)	VSWR-T (3:1)
1.2	25	140	7.48	16.3	61.4	-14.9	S	Р
1.3	25	136	7.35	15.8	61.3	-13.5	S	Р
1.4	25	127	7.07	14.7	61.8	-13.9	S	Р

Gain vs. Frequency



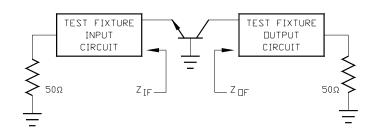
#### **Collector Efficiency vs. Frequency**



#### **RF Test Fixture Impedance**

2

F (GHz)	Z <sub>IF</sub> (Ω)	Z <sub>OF</sub> (Ω)		
1.2	2.6 - j3.8	3.0 - j2.7		
1.3	3.0 - j3.4	2.4 - j2.6		
1.4	3.4 - j3.1	1.9 - j2.5		



ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed. PRELIMINARY: Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Momitment to produce in volume is not guaranteed.

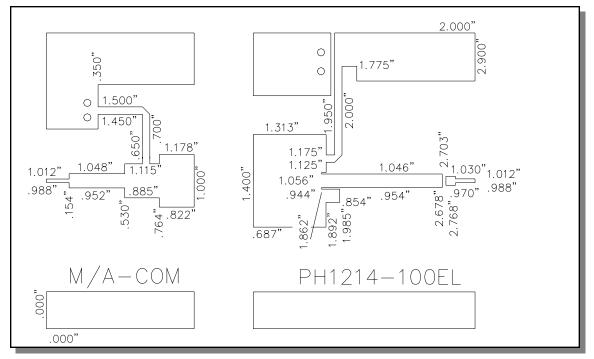
- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
  Visit www.macomtech.com for additional data sheets and product information.

M/A-COM Technology Solutions Inc. and its affiliates reserve the right to make changes tracher products) by in ormation contained herein without notice.

# PH1214-100EL

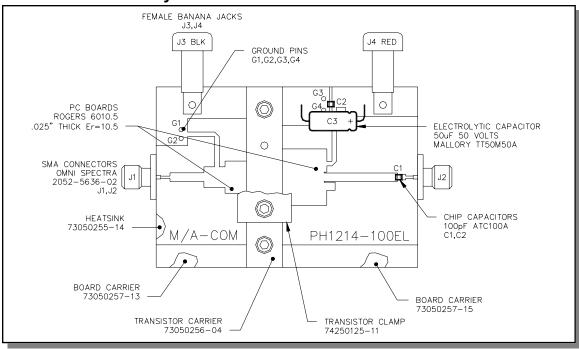
# Radar Pulsed Power Transistor 100W, 1.2-1.4 GHz, 2ms Pulse, 20% Duty

#### **Test Fixture Circuit Dimensions**



#### **Test Fixture Assembly**

3



ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed. **PRELIMINARY:** Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

M/A-COM Technology Solutions Inc. and its affiliates reserve the right to make cleanges (whe products) by information contained herein without notice.

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macomtech.com for additional data sheets and product information.



### M/A-COM Products Released, 30 May 07